

View Online at <https://aerobasegroup.com/nsn/5961-00-493-0789>

Inclosure Material:

Metal

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

15.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

10.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector absolute all transistor

Transfer Ratio:

40.0 static forward current transfer ratio, common-emitter all transistor

Special Features:

All transistor junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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